

EMIF06-HSD03F3

EMI filter with integrated ESD protection for micro-SD Card™



Figure 1. Pin configuration (bump side)



Figure 2. Functional schematic



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Datasheet – production data

Features

- Very low line capacitance to compensate long PCB tracks (2.5 pF typ.)
- High efficiency in ESD suppression up to 18 kV (IEC 61000-4-2)
- Very low PCB space consumption:
 - 1.1 x 2.4 mm
- Ultralow leakage current: 20 nA max.
- Very thin package: 0.605 mm
- Smart pinout for easier PCB layout
- High reduction of parasitic elements through integration and wafer level packaging
- Lead-free package
- Complies with the following standards:
 - IEC 61000-4-2 level 4:±15 kV (air discharge), ±8 kV (contact discharge)

Application

• SD3.0, UHS-1 SDR104 (208 MHz)

Description

The EMIF06-HSD03F3 chip is a highly integrated device designed to suppress EMI/RFI noise for interface line filtering.

The EMIF06-HSD03F3 Flip-Chip packaging means the package size is equal to the die size. That's why EMIF06-HSD03F3 is a very small device. Additionally, this filter includes ESD protection circuitry, which prevents damage to the protected device when subjected to ESD surges up 18 kV.

This is information on a product in full production.

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1 Application diagram



Figure 3. Schema



2 Characteristics

Symbol	Parameter	Value	Unit
V _{PP}	ESD discharge IEC 61000-4-2, level 4 for Ix pins: Air discharge Contact discharge ESD discharge IEC 61000-4-2, level 1 for Ox pins: Air discharge Contact discharge	18 18 10 10	kV
Тj	Maximum junction temperature	125	°C
T _{OP}	Operating temperature range	- 30 to + 85	°C
T _{stg}	Storage temperature range	- 55 to +150	°C

Table 1. Absolute maximum	ratings	(T _{amb} = 25 °C)
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Figure 4. Electrical characteristics (definitions)





Symbol	Test conditions			Тур.	Max.	Unit	
V_{BR}	Data lines, I _R = 1 mA		5		9	V	
I _{RM}	V _{RM} = 3 V per line				20	nA	
R _{I/O}				1		Ω	
C _{line}	$V_{\text{line}} = 0 \text{ V}, V_{\text{osc}} = 30 \text{ mV}, \text{ F} = 1 \text{ MHz}$			2.5	3	pF	
L				1		nH	
Rd	Dunamica registence, t 100 pc	IO-GND (positive polarity)		650			
	Dynamics resistance, t _P = 100 ns	GND-IO (negative polarity)		320		mΩ	
V _{cc}		·					
V_{BR}	I _R = 1 mA		5		9	V	
I _{RM}	V _{RM} = 3 V				20	nA	
C _{line}	$V_{\text{line}} = 0 \text{ V}, V_{\text{osc}} = 30 \text{ mV}, \text{F} = 1 \text{ MHz}$			40		pF	
DET							
V_{BR}	I _R = 1 mA		5		9	V	
I _{RM}	V _{RM} = 3 V				20	nA	
C _{line}	$V_{\text{line}} = 0 \text{ V}, V_{\text{osc}} = 30 \text{ mV}, \text{ F} = 1 \text{ MHz}$			40		pF	

Table 2.	Electrical	characteristics	(Tomb = 25	°C)
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Figure 11. TLP measurement



3 Package information

- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK[®] is an ST trademark.

3.1 Flip-Chip package information



Figure 12. Flip-Chip package dimensions



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Note: More information is available in the application notes:
 AN2348, "IPAD[™] 400 µm Flip Chip: package description and recommendations for use"
 AN1751, "EMI filters: recommendations and measurements"
 AN4541: "EMI Filters for SD3.0 card: High speed SD card protection and filtering devices"



4 Ordering information

Figure 16. Ordering information scheme EMIF 06 - HSD 03 F3 EMI Filter Image: Colspan="2">Image: Colspan="2">Image: Colspan="2">Image: Colspan="2">Image: Colspan="2">Image: Colspan="2">Image: Colspan="2">Image: Colspan="2" EMI Filter Image: Colspan="2">Image: Colspan="2" Number of lines Image: Colspan="2">Image: Colspan="2"

HSD = High speed SD card

Version

Version = 3

Application

Package

F = Flip Chip

x = 3: Lead-free, pitch = 400 μ m, bump = 255 μ m

Table 3. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
EMIF06-HSD03F3	KK	Flip Chip	3.4 mg	5000	Tape and reel (7")

5 Revision history

Table 4. Document revision history

Date	Revision	Changes
19-Nov-2013	1	Initial release
09-Jan-2014	2	Corrected typographical error.
06-Jan-2015	3	Added mention for new AN4541.
06-Oct-2016		Updated Figure 1.



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